



# UTT50P04

**Power MOSFET**

## -40V, -50A P-CHANNEL POWER MOSFET

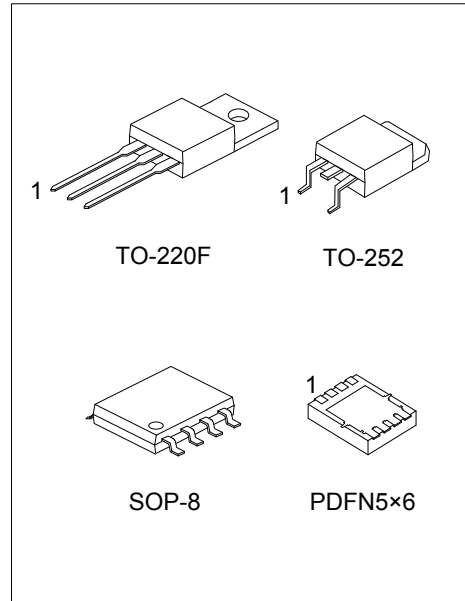
### DESCRIPTION

The UTC **UTT50P04** is a P-channel power MOSFET using UTC's advanced technology to provide the customers with high switching speed and a minimum on-state resistance, and it can also withstand high energy in the avalanche.

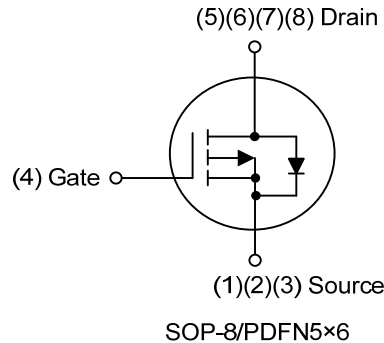
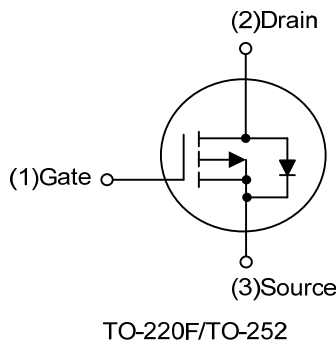
This UTC **UTT50P04** is suitable for motor drivers, high-side switch and 12V board net, etc.

### FEATURES

- \*  $R_{DS(ON)} \leq 15 \text{ m}\Omega$  @  $V_{GS} = -10\text{V}$ ,  $I_D = -30\text{A}$
- $R_{DS(ON)} \leq 25 \text{ m}\Omega$  @  $V_{GS} = -4.5\text{V}$ ,  $I_D = -20\text{A}$
- \* High Switching Speed



### SYMBOL



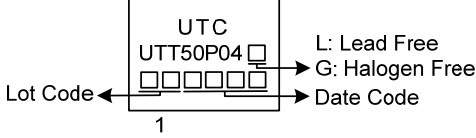
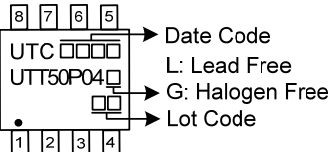
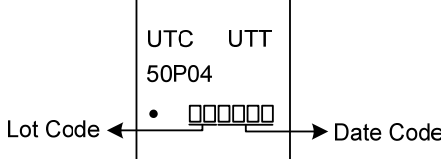
### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UTT50P04L-TF3-T	UTT50P04G-TF3-T	TO-220F	G	D	S	-	-	-	-	-	Tape Reel
UTT50P04L-TN3-R	UTT50P04G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
UTT50P04L-S08-R	UTT50P04G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel
UTT50P04L-P5060-R	UTT50P04G-P5060-R	PDFN5x6	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>UTT50P04G-TF3-T</p> <p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Green Package</p>	<p>(1) R: Tape Reel</p> <p>(2) TF3: TO-220F, TN3: TO-252, S08: SOP-8 P5060: PDFN5x6</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ MARKING

PACKAGE	MARKING
TO-220F / TO-252	 <p style="text-align: center;">1</p>
SOP-8	
PDFN5×6	

■ ABSOLUTE MAXIMUM RATINGS ( $T_C=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	-40	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Drain Current	Continuous	$I_D$	-50 (Note 2)	A
	Pulsed	$I_{DM}$	-100	A
Continuous Source Current (Diode Conduction)		$I_S$	-50 (Note 2)	A
Avalanche Current		$I_{AR}$	-40	A
Avalanche Energy		$E_{AS}$	80	mJ
Power Dissipation	TO-220F	$P_D$	38	W
	TO-252		56	W
	SOP-8		2.2	W
	PDFN5x6		12	W
Junction Temperature		$T_J$	-55 ~ +150	$^{\circ}\text{C}$
Storage Temperature		$T_{STG}$	-55 ~ +150	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220F/TO-252	$\theta_{JA}$	110	$^{\circ}\text{C/W}$
	SOP-8		100 (Note 2)	$^{\circ}\text{C/W}$
	PDFN5x6		65 (Note 2)	$^{\circ}\text{C/W}$
Junction to Case	TO-220F	$\theta_{JC}$	3.28	$^{\circ}\text{C/W}$
	TO-252		2.5 (Note 2)	$^{\circ}\text{C/W}$
	SOP-8		56 (Note 2)	$^{\circ}\text{C/W}$
	PDFN5x6		10.4 (Note 2)	$^{\circ}\text{C/W}$

Notes: 1. Calculated based on maximum allowable Junction Temperature. Package limitation current is 50A.  
2. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

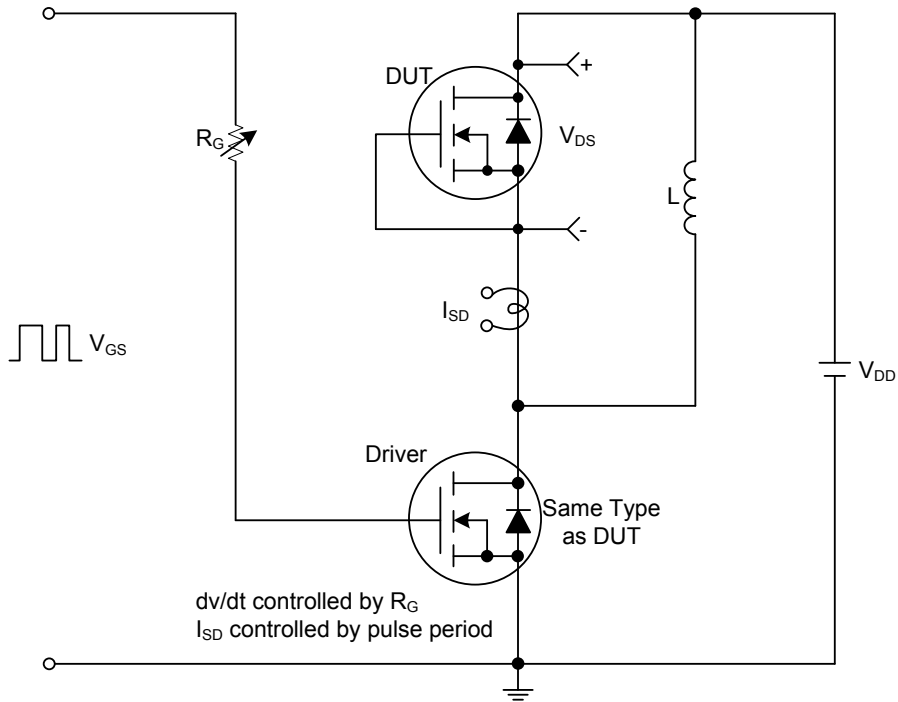
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =-250μA, V <sub>GS</sub> =0V	-40			V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V			-1	μA
Gate- Source Leakage Current	Forward	V <sub>GS</sub> =+20V, V <sub>DS</sub> =0V			+100	nA
	Reverse	V <sub>GS</sub> =-20V, V <sub>DS</sub> =0V			-100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.0		-3.0	V
Static Drain-Source On-State Resistance (Note 1)	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-30A			15	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A			25	mΩ
<b>DYNAMIC PARAMETERS (Note 2)</b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1MHz		2930		pF
Output Capacitance	C <sub>OSS</sub>			385		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			291		pF
<b>SWITCHING PARAMETERS (Note 2)</b>						
Total Gate Charge (Note 3)	Q <sub>G</sub>	V <sub>GS</sub> =-5V, V <sub>DS</sub> =-32V, I <sub>D</sub> =-50A		32.5		nC
		V <sub>GS</sub> =-10V, V <sub>DS</sub> =-32V, I <sub>D</sub> =-50A		57.8		nC
Gate to Source Charge (Note 3)	Q <sub>GS</sub>	I <sub>G</sub> =1mA		8		nC
Gate to Drain Charge (Note 3)	Q <sub>GD</sub>			16		nC
Turn-ON Delay Time (Note 3)	t <sub>D(ON)</sub>	V <sub>DD</sub> =-20V, V <sub>GEN</sub> =-10V, I <sub>D</sub> ≈-50A, R <sub>L</sub> =0.4Ω, R <sub>G</sub> =3Ω		11		ns
Rise Time (Note 3)	t <sub>R</sub>			18		ns
Turn-OFF Delay Time (Note 3)	t <sub>D(OFF)</sub>			53		ns
Fall-Time (Note 3)	t <sub>F</sub>			36		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub>=25°C)</b>						
Maximum Body-Diode Pulsed Current	I <sub>SM</sub>				-50	A
Drain-Source Diode Forward Voltage (Note 1)	V <sub>SD</sub>	I <sub>F</sub> =-50A, V <sub>GS</sub> =0V			-1.5	V
Reverse Recovery Time (Note 1)	t <sub>rr</sub>	I <sub>S</sub> =-30A, V <sub>GS</sub> =0V,		72		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt=100A/μs		100		nC

Notes: 1. Pulse test; pulse width ≤ 300μs, duty cycle ≤ 2%.

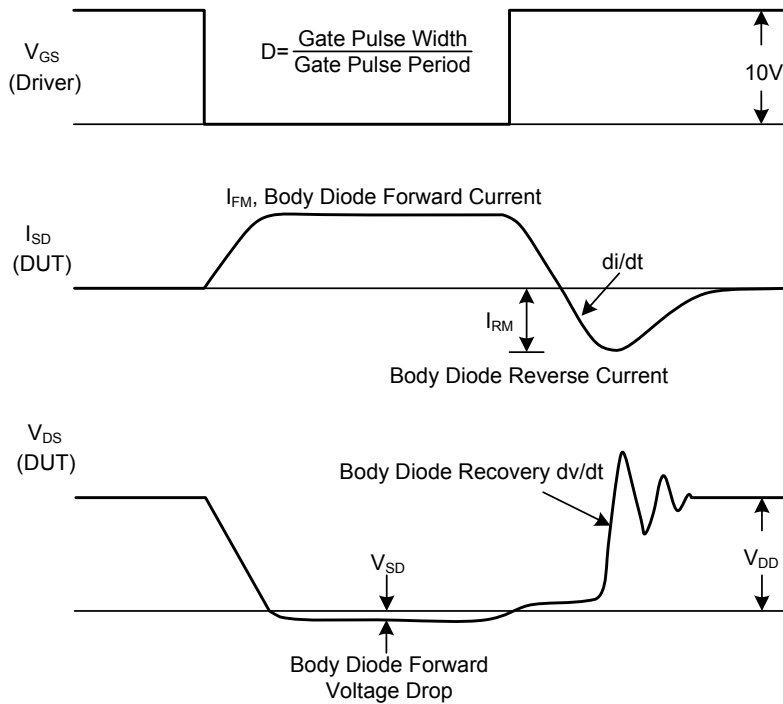
2. Guaranteed by design, not subject to production testing.

3. Independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS



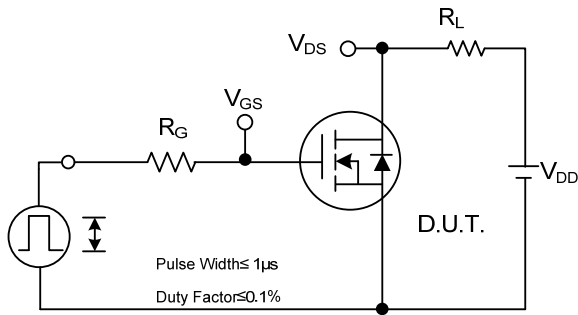
Peak Diode Recovery dv/dt Test Circuit



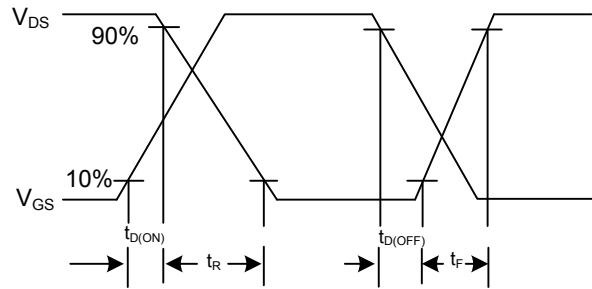
Peak Diode Recovery dv/dt Test Circuit and Waveforms

Peak Diode Recovery dv/dt Waveforms

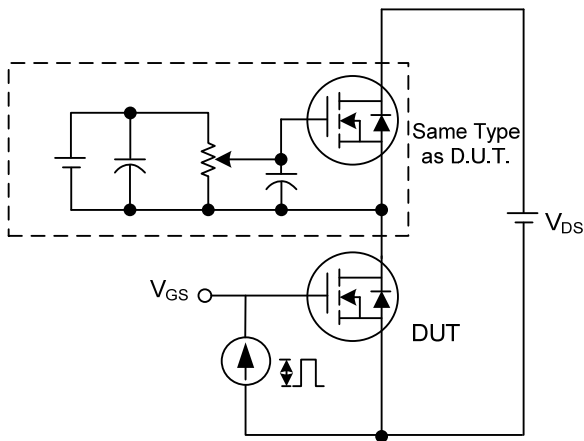
## TEST CIRCUITS AND WAVEFORMS



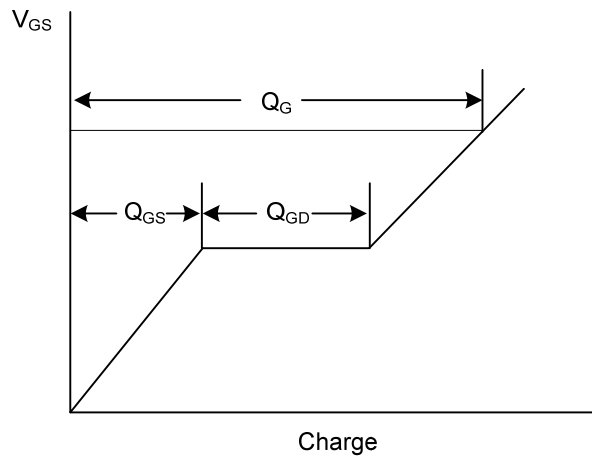
**Switching Test Circuit**



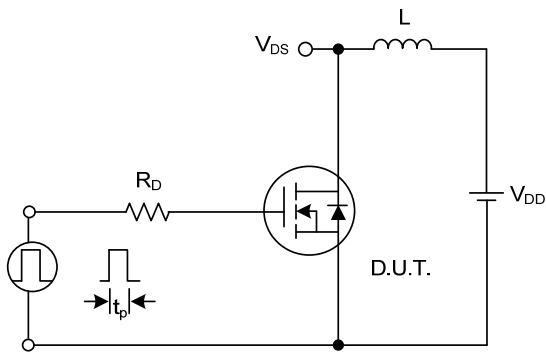
**Switching Waveforms**



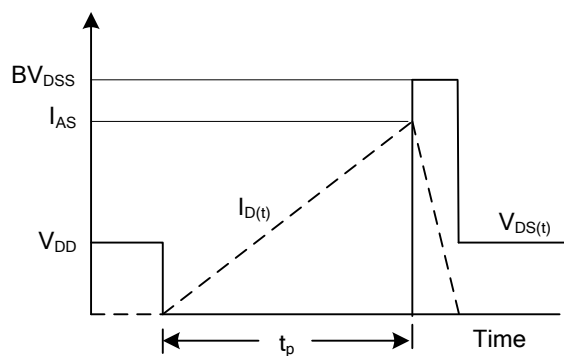
**Gate Charge Test Circuit**



**Gate Charge Waveform**

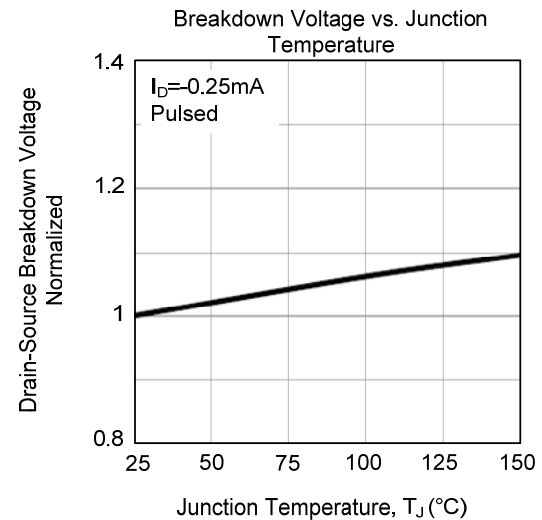
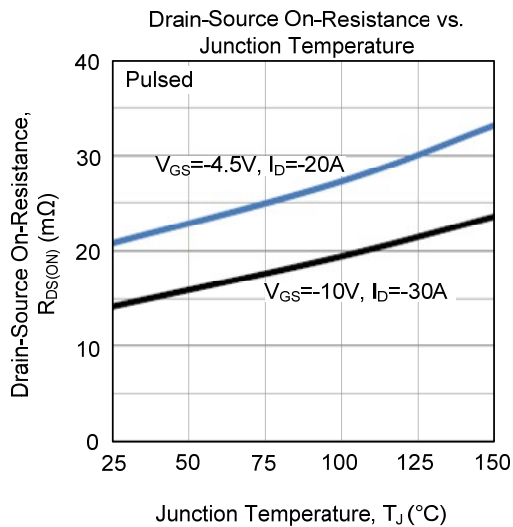
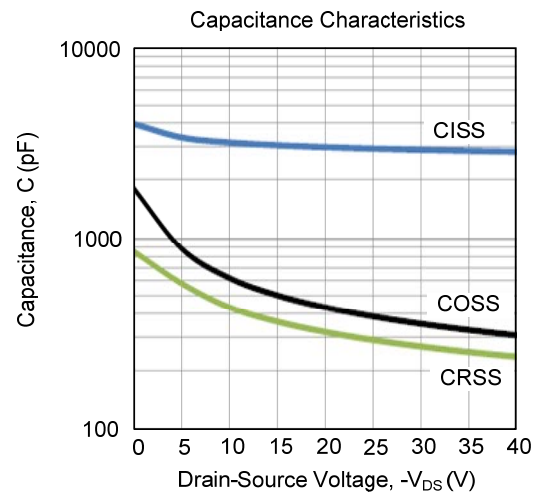
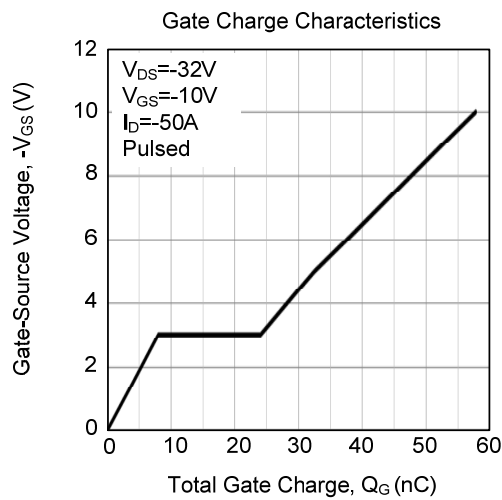
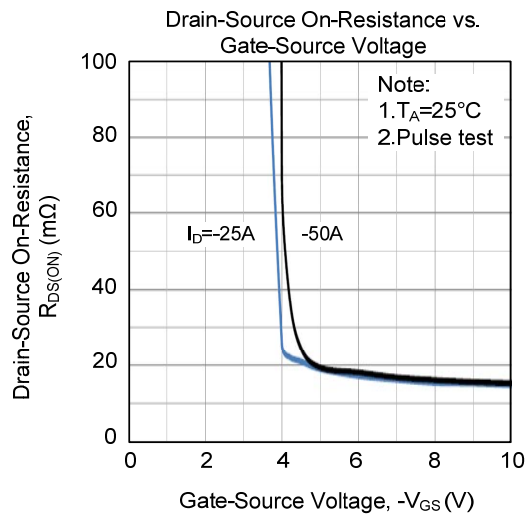
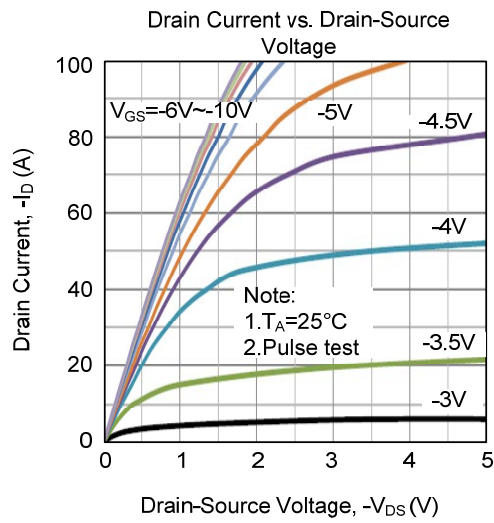


**Unclamped Inductive Switching Test Circuit**

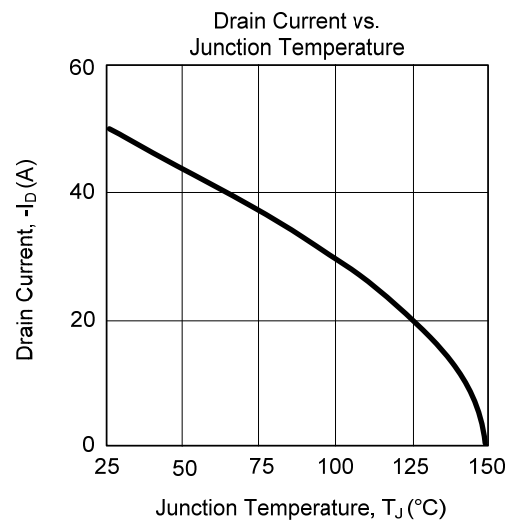
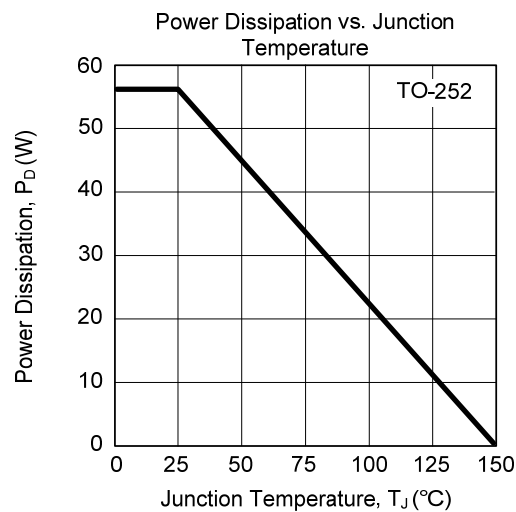
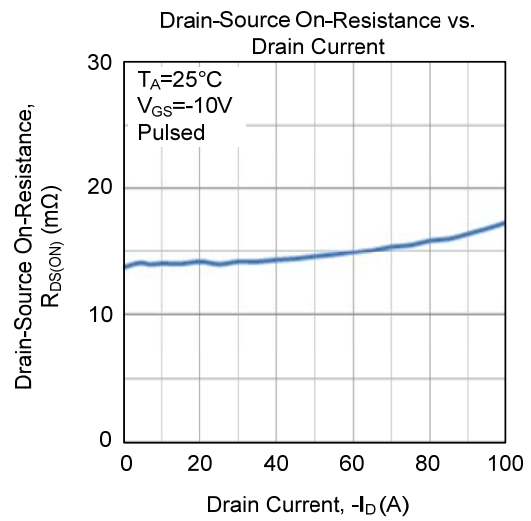
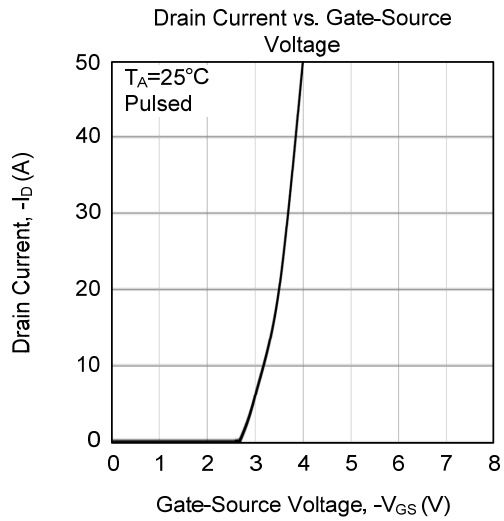
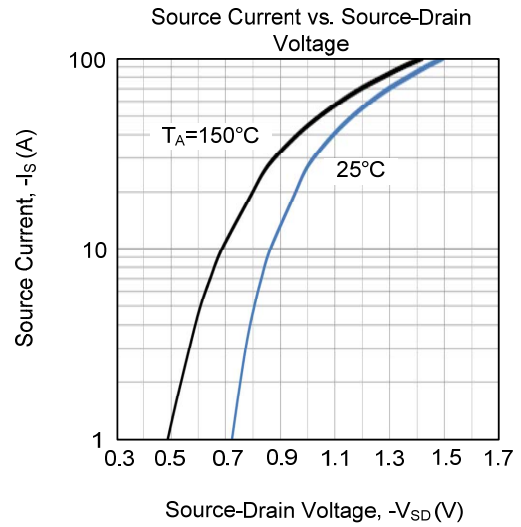
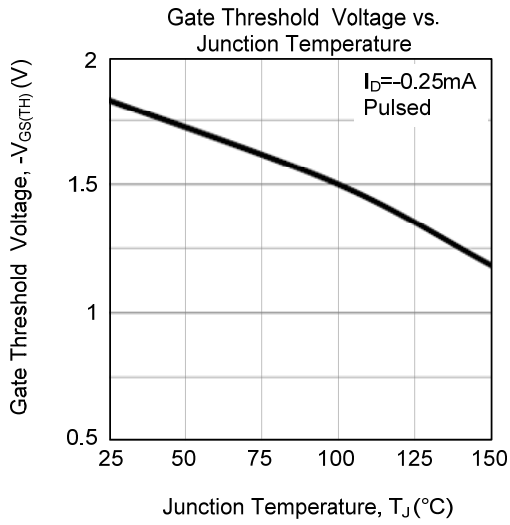


**Unclamped Inductive Switching Waveforms**

## TYPICAL CHARACTERISTICS

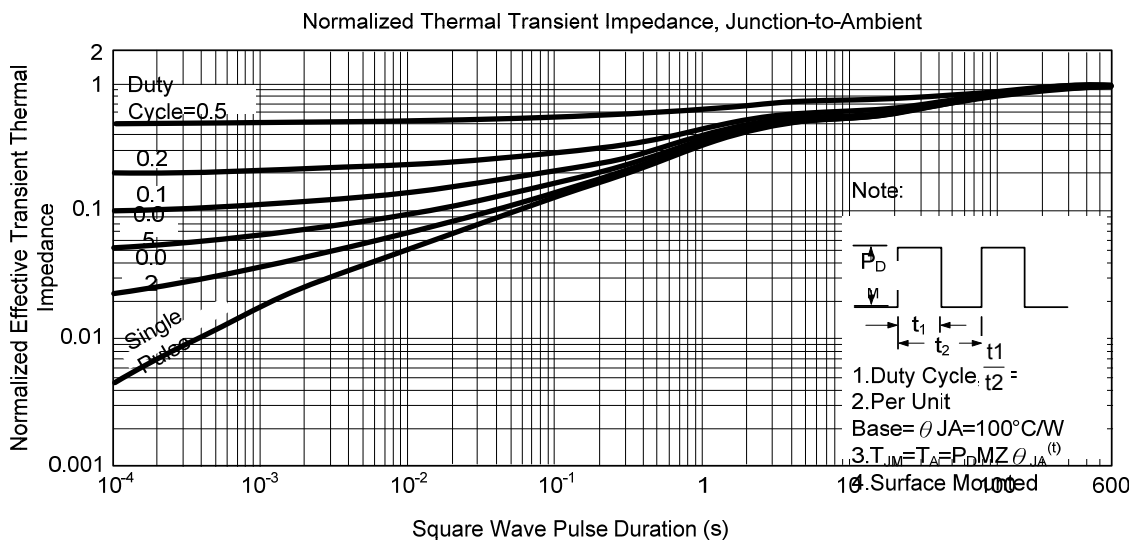
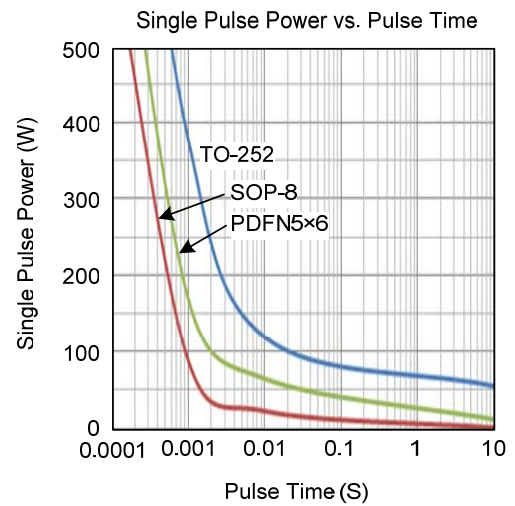
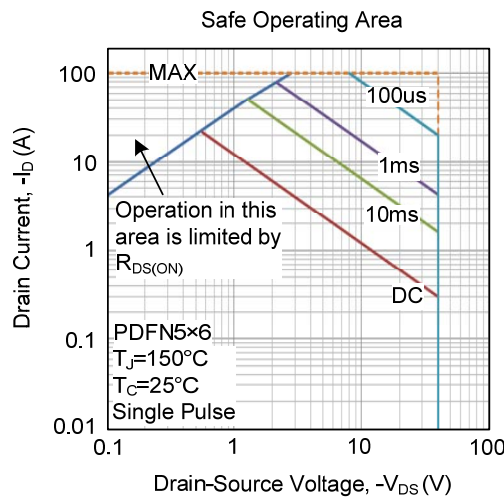
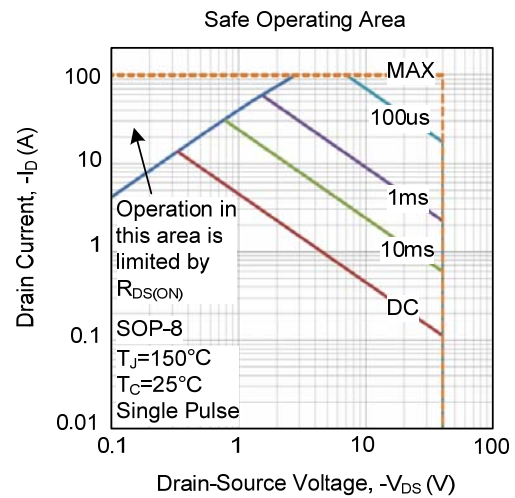
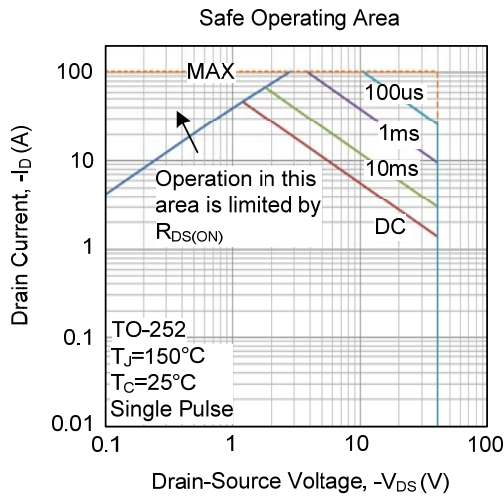


## ■ TYPICAL CHARACTERISTICS (Cont.)





## ■ TYPICAL CHARACTERISTICS (Cont.)



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[MCQ7328-TP](#) [SSM3J143TU,LXHF](#) [DMN12M3UCA6-7](#) [PJMF280N65E1\\_T0\\_00201](#) [PJMF380N65E1\\_T0\\_00201](#)  
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